SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004

HIGH-VOLTAGE HIGH-CURRENT DARLINGTON TRANSISTOR ARRAYS

• 500-mA Rated Collector Current (Single SN75468 . . . D, N, OR NS PACKAGE **Output)** SN75469 . . . D OR N PACKAGE (TOP VIEW) High-Voltage Outputs ... 100 V Output Clamp Diodes 1B 16 1 1C 2B 🛛 15 🛛 2C Inputs Compatible With Various Types of 2 14 3C 3B 🛛 Logic 3 4B 🛛 4 13 1 4C Relay Driver Applications 5B 🛙 5 12 5C Higher-Voltage Versions of ULN2003A and 6B 🛛 6 11 6C ULN2004A, for Commercial Temperature 7B 🛛 10 7C 7 Range 9 COM Е 8

description/ordering information

The SN75468 and SN75469 are high-voltage, high-current Darlington transistor arrays. Each consists of seven npn Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads. The collector-current rating of each Darlington pair is 500 mA. The Darlington pairs may be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers.

The SN75468 has a 2700- Ω series base resistor for each Darlington pair for operation directly with TTL or 5-V CMOS. The SN75469 has a 10.5-k Ω series base resistor to allow its operation directly with CMOS or PMOS that use supply voltages of 6 to 15 V. The required input current is below that of the SN75468.

T _A	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	PDIP (N)	Tube of 25	SN75468N	SN75468N	
		Tube of 40	SN75468D	0175 (00	
	SOIC (D)	Reel of 2500	SN75468DR	SN75468	
0°C to 70°C	SOP (NS)	Reel of 2000	SN75468NSR	SN75468	
	PDIP (N)	Tube of 25	SN75469N	SN75469N	
	SOIC (D)	Tube of 40	SN75469D	SN75469	
		Reel of 2500	SN75469DR	311/0409	

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

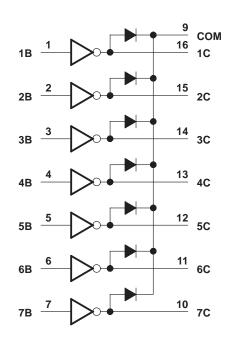
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



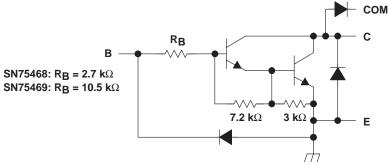
Copyright © 2004, Texas Instruments Incorporated

SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004

logic diagram



schematic (each Darlington pair)



All resistor values shown are nominal.



SLRS023D – DECEMBER 1976 – REVISED NOVEMBER 2004

absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)[†]

Collector-emitter voltage, V _{CE}	
Input voltage, V _I (see Note 1)	
Peak collector current (see Figures 14 and 15)	
Output clamp current, I _{OK}	500 mA
Total emitter-terminal current	–2.5 A
Package thermal impedance, θ_{JA} (see Notes 2 and 3): D	package
Ν	l package 67°C/W
Ν	IS package 64°C/W
Operating virtual junction temperature, T _J	
Storage temperature range, T _{stg}	−65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

- 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.



SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004

electrical characteristics, $T_A = 25^{\circ}C$ (unless otherwise noted)

PARAMETER		TEST		S	N75468		SN75469					
		FIGURE	TEST CO	TEST CONDITIONS		TYP	MAX	MIN	TYP	MAX	UNIT	
				I _C = 125 mA						5		
				I _C = 200 mA			2.4			6		
M	On state innut valte as	5		I _C = 250 mA			2.7				V	
V _{I(on)}	On-state input voltage	Э	V _{CE} = 2 V	I _C = 275 mA						7	V	
				I _C = 300 mA			3					
				I _C = 350 mA						8		
	0 "		I _I = 250 μA,	I _C = 100 mA		0.9	1.1		0.9	1.1		
	Collector-emitter saturation voltage	6	I _I = 350 μA,	I _C = 200 mA		1	1.3		1	1.3	V	
	Saturation voltage		I _I = 500 μA,	I _C = 350 mA		1.2	1.6		1.2	1.6		
VF	Clamp-diode forward voltage	8	IF = 350 mA			1.7	2		1.7	2	V	
			V _{CE} = 100 V,	$I_{I} = 0$			50			50		
ICEX	Collector cutoff current	1	V _{CE} = 100 V,	$I_{I} = 0$			100			100	μA	
		2	$T_A = 70^{\circ}C$	V _I = 1 V						500		
I _{I(off)}	Off-state input current	3	$V_{CE} = 50 \text{ V},$ $T_{A} = 70^{\circ}\text{C}$	l _C = 500 μA,	50	65		50	65		μA	
			VI = 3.85 V			0.93	1.35					
lj –	Input current	4	V _I = 5 V						0.35	0.5	mA	
-			V _I = 12 V						1	1.45		
	Clamp-diode reverse	-	V _R = 100 V				50			50	•	
I _R	current	7	V _R = 100 V,	$T_A = 70^{\circ}C$			100			100	μA	
Ci	Input capacitance		$V_{I} = 0,$	f = 1 MHz		15	25		15	25	pF	

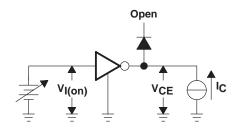
switching characteristics, $T_{\mbox{\scriptsize A}}$ = 25°C free-air temperature

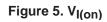
	PARAMETER	Т	EST CONDITIO	MIN	TYP	MAX	UNIT	
^t PLH	Propagation delay time, low-to-high-level output	V _S = 50 V,	RL = 163 Ω,	C _L = 15 pF,		0.25	1	μs
^t PHL	Propagation delay time, high-to-low-level output	See Figure 9				0.25	1	μs
VOH	High-level output voltage after switching	V _S = 50 V,	$I_{O} \approx 300 \text{ mA},$	See Figure 10	V _S – 20			mV



SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004

Open VCE $figure 1. I_{CEX}$ V_{CE} $V_{$





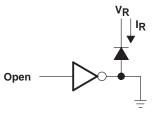
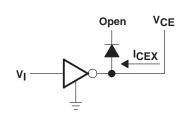


Figure 7. I_R



PARAMETER MEASUREMENT INFORMATION

Figure 2. I_{CEX}

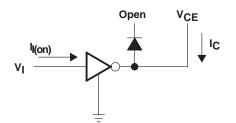
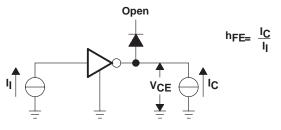


Figure 4. I_I



NOTE: II is fixed for measuring VCE(sat), variable for measuring hFE.

Figure 6. h_{FE}, V_{CE(sat)}

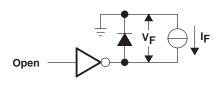
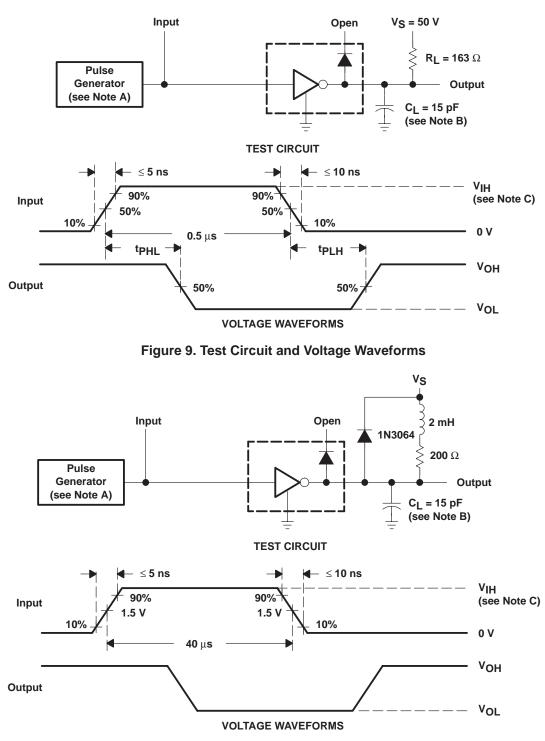


Figure 8. V_F



SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004



PARAMETER MEASUREMENT INFORMATION



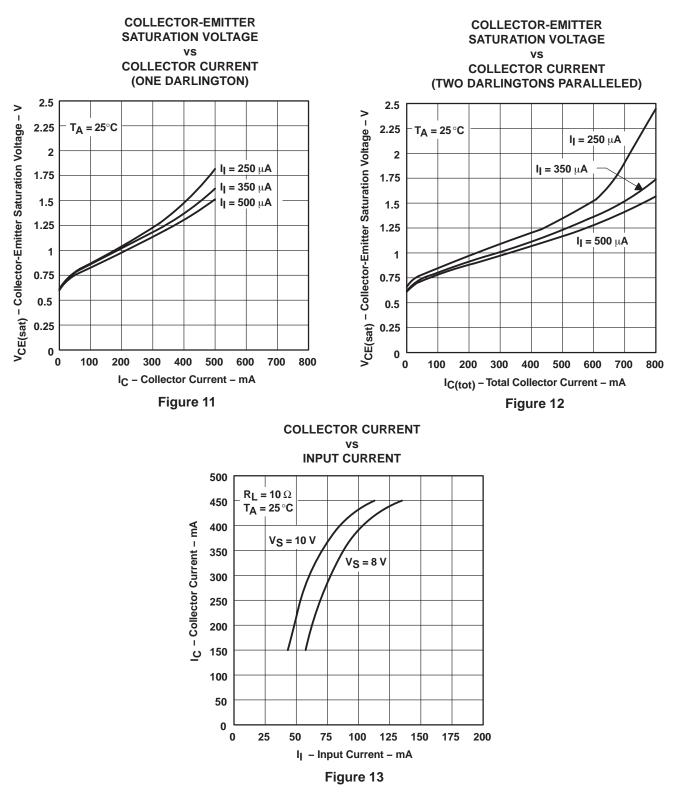
NOTES: A. The pulse generator has the following characteristics: PRR = 12.5 kHz, Z_0 = 50 Ω .

- B. Cl includes probe and jig capacitance.
- C. For testing the '468, $V_{IH} = 3$ V; for the '469, $V_{IH} = 8$ V.



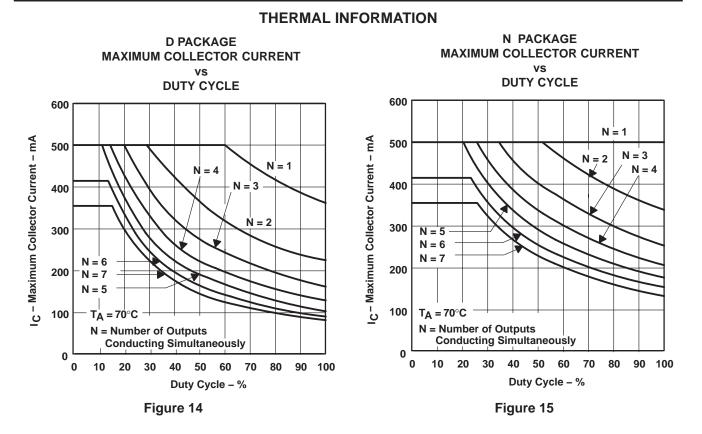
SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004

TYPICAL CHARACTERISTICS



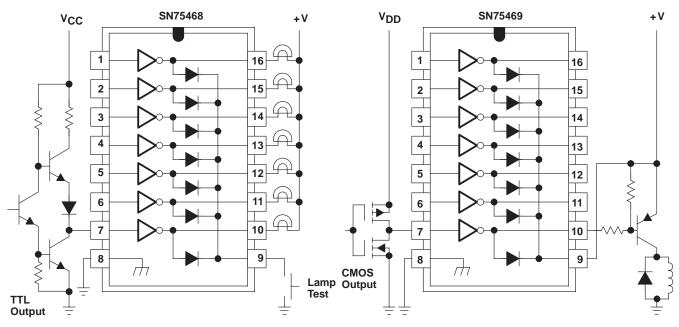


SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

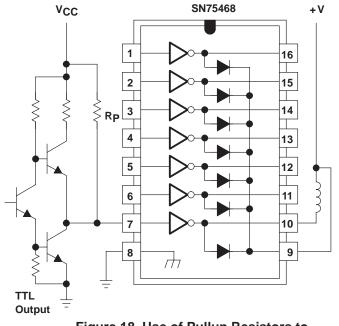
SLRS023D - DECEMBER 1976 - REVISED NOVEMBER 2004

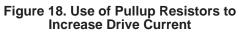


APPLICATION INFORMATION

Figure 16. TTL to Load

Figure 17. Buffer for Higher Current Loads







4-Jun-2007

PACKAGING INFORMATION

TEXAS

www.ti.com

JMENTS

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75468D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468DE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468DRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468N	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75468NE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75468NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468NSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75468NSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75469D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75469DE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75469DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75469DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75469DRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75469DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75469N	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75469NE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered



at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*Al	dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	SN75468NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
	SN75469DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75468NSR	SO	NS	16	2000	346.0	346.0	33.0
SN75469DR	SOIC	D	16	2500	333.2	345.9	28.6

MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AC.



D(R-PDSO-G16)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Clocks and Timers	www.ti.com/clocks	Digital Control	www.ti.com/digitalcontrol
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
RFID	www.ti-rfid.com	Telephony	www.ti.com/telephony
RF/IF and ZigBee® Solutions	www.ti.com/lprf	Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2008, Texas Instruments Incorporated